



ITW

PATENT APPLICATION
Docket No. 9898-321
Client No. SS-18146-US

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of: Ki-Yeon PARK, et al.

Serial No. 10/713,577 Examiner: Nhu, David

Filed: November 12, 2003 Group Art Unit: 2818

Confirmation No. 8248

For: CAPACITOR OF SEMICONDUCTOR MEMORY DEVICE THAT
HAS COMPOSITE $\text{Al}_2\text{O}_3/\text{HfO}_2$ DIELECTRIC LAYER AND
METHOD OF MANUFACTURING THE SAME

TRANSMITTAL LETTER

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Enclosed for filing in the above-referenced application are the following:

- ☒ Response to Restriction Requirement
- ☒ A copy of the Limited Recognition Under 37 CFR § 10.9(b).
- ☒ Return Post Card
- ☒ Any deficiency or overpayment should be charged or credited to deposit account number 13-1703.

Customer No. 20575

Respectfully submitted,

MARGER JOHNSON & McCOLLOM, P.C.

Hosoon Lee
Limited Recognition Under 37 CFR § 10.9(b).

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Date: November 15, 2004

Li Mei Vermilya